

# 30A02MH

# Low-Frequency General-Purpose Amplifier Applications

An ON Semiconductor Company

# **Applications**

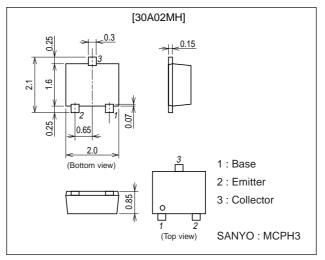
 Low-frequency Amplifier, high-speed switching, small motor drive.

#### **Features**

- · Large current capacitance.
- Low collector-to-emitter saturation voltage (resistance). RCE(sat) typ= $580m\Omega[IC=0.7A, IB=35mA]$ .
- · Small ON-resistance (Ron).

# **Package Dimensions**

unit : mm 2194A



# **Specifications**

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-30	V
Collector-to-Emitter Voltage	VCEO		-30	V
Emitter-to-Base Voltage	VEBO		-5	V
Collector Current	IC		-700	mA
Collector Current (Pulse)	ICP		-1.4	Α
Collector Dissipation	PC	Mounted on a ceramic board (600mm <sup>2</sup> X0.8mm)	600	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linis
			min	typ	max	Unit
Collector Cutoff Current	ІСВО	V <sub>CB</sub> =-30V, I <sub>E</sub> =0			-100	nA
Emitter Cutoff Current	IEBO	VEB=-4V, IC=0			-100	nA
DC Current Gain	hFE	V <sub>CE</sub> =-2V, I <sub>C</sub> =-10mA	200		500	
Gain-Bandwidth Product	fT	V <sub>CE</sub> =-10V, I <sub>C</sub> =-50mA		520		MHz
Output Capacitance	Cob	V <sub>CB</sub> =-10V, f=1MHz		4.7		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =-200mA, I <sub>B</sub> =-10mA		-110	-220	mV
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	IC=-200mA, IB=-10mA		-0.9	-1.2	V

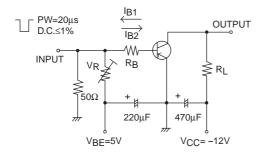
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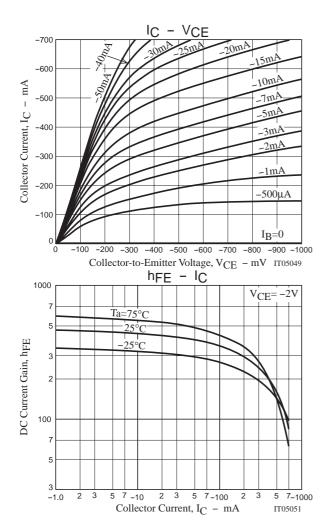
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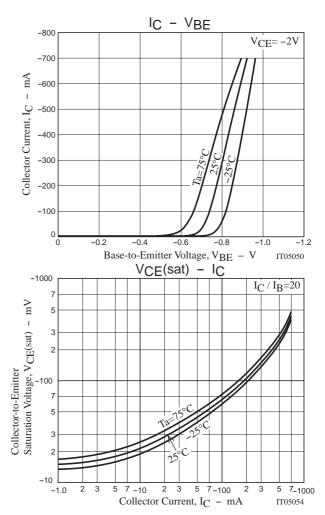
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =-10μA, I <sub>E</sub> =0	-30			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=-1mA, RBE=∞	-30			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=-10μA, IC=0	-5			V
Turn-ON Time	ton	See specified Test Circuit.		35		ns
Storage Time	t <sub>stg</sub>	See specified Test Circuit.		125		ns
Fall Time	tf	See specified Test Circuit.		25		ns

### **Switching Time Test Circuit**

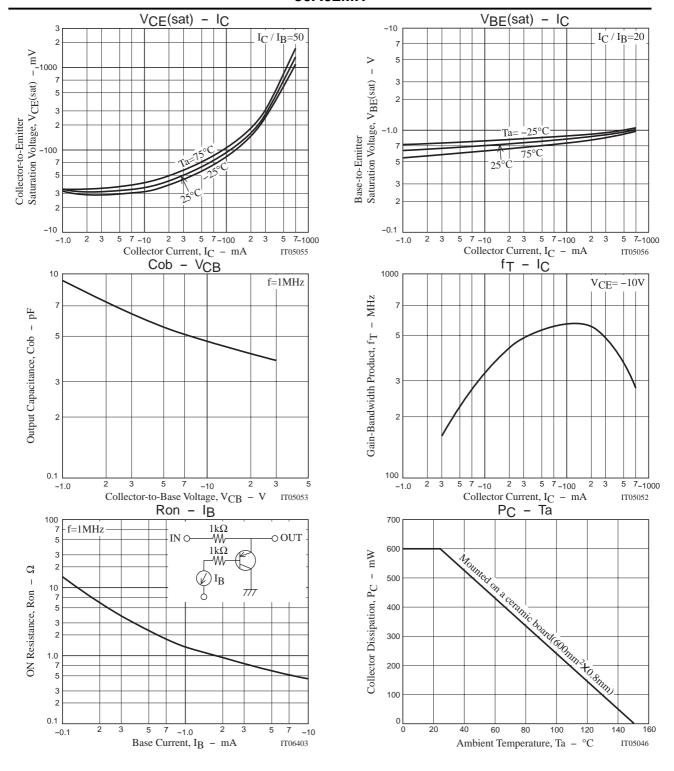


 $I_{C}=20I_{B1}=-20I_{B2}=-300mA$ 





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